

N-Channel 60-V (D-S) MOSFET

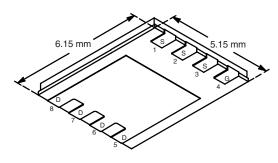
PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)			
60	0.011 at V _{GS} = 10 V	15.8			
	0.013 at V _{GS} = 6 V	14.5			

FEATURES

- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET® Power MOSFET
- New Low Thermal Resistance PowerPAK® Package with Low 1.07 mm Profile
- PWM Optimized for Fast Switching
- 100 % R_q Tested

HALOGEN **FREE**

PowerPAK SO-8

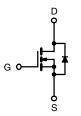


Bottom View

Ordering Information: Si7370DP-T1-E3 (Lead (Pb)-free) Si7370DP-T1-GE3 (Lead (Pb)-free and Halogen-free)

APPLICATIONS

- Primary Side Switch for 24 V DC/DC Applications
- Secondary Synchronous Rectifier



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS $T_A = 25 ^{\circ}\text{C}$, unle Parameter		Symbol	10 s	Steady State	Unit	
			103	·	Oiiit	
Drain-Source Voltage		V_{DS}	60		V	
Gate-Source Voltage		V_{GS}	:	•		
Continuous Drain Current (T _{.I} = 150°C) ^a	T _A = 25 °C	I _D	15.8	9.6		
Continuous Diain Current (1) = 150 C)	T _A = 70 °C		12.6	7.7		
Continuous Source Current		I _S	4.7	1.7	Α	
Pulsed Drain Current		I _{DM}	50			
Avalanche Current		I _{AS}	50			
Single Avalanche Energy		E _{AS}	125		mJ	
Maximum Power Dissipation	T _A = 25 °C	P _D	5.2	1.9	W	
Maximum Fower Dissipation	T _A = 70 °C	- 'D	3.3	1.25	vv	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	
Soldering Recommendations (Peak Temperature) ^{b, c}			260			

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Manines une lumetien te Ameleian tâ	t ≤ 10 s	R _{thJA}	19	24		
Maximum Junction-to-Ambient ^a	Steady State		52	65	°C/W	
Maximum Junction-to-Case (Drain)	Steady State	R_{thJC}	1.5	1.8		

Notes

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Solder Profile (www.vishay.com/ppg?73257). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

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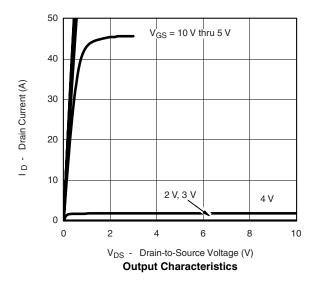
SPECIFICATIONS $T_J = 25$ °C	C, unless c	otherwise noted					
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	2.0		4.0	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zarra Cata Valtana Dunin Comunat		V _{DS} = 60 V, V _{GS} = 0 V			1		
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			5	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	50			Α	
	D	V _{GS} = 10 V, I _D = 12 A		0.009	0.011		
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 6.0 V, I _D = 10 A 0.010		0.0105	0.013	Ω	
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 10 A		50		S	
Diode Forward Voltage ^a	V_{SD}	I _S = 3.0 A, V _{GS} = 0 V		0.75	1.2	V	
Dynamic ^b							
Total Gate Charge	Q_g			46	57		
Gate-Source Charge	Q_{gs}	$V_{DS} = 30 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 12 \text{ A}$		11.5		nC	
Gate-Drain Charge	Q _{gd}			11.5			
Gate Resistance	R_g		0.2	0.85	1.2	Ω	
Turn-On Delay Time	t _{d(on)}			16	25		
Rise Time	t _r	V_{DD} = 30 V, R_L = 30 Ω		12	18	ns	
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ 1.0 A, V_{GEN} = 10 V, R_G = 6 Ω		50	75		
Fall Time	t _f			30	45		
Source-Drain Reverse Recovery Time	t _{rr}	$I_F = 3.0 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}$		40	60		

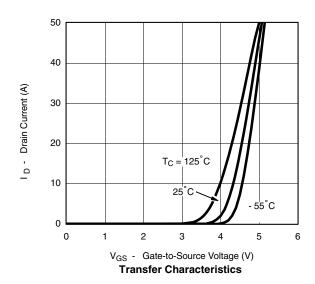
Notes

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



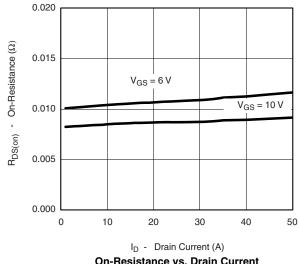




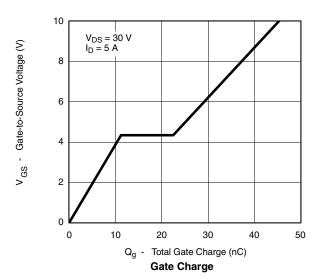


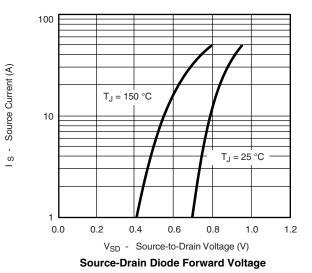


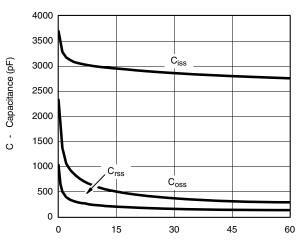
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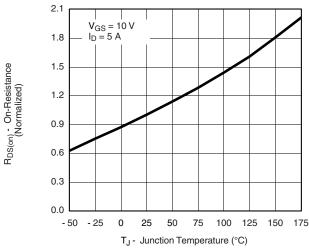
On-Resistance vs. Drain Current



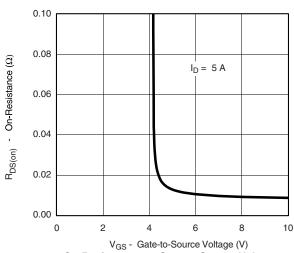




 V_{DS} - Drain-to-Source Voltage (V) Capacitance



On-Resistance vs. Junction Temperature

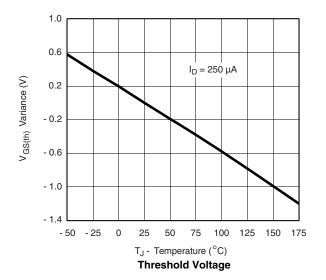


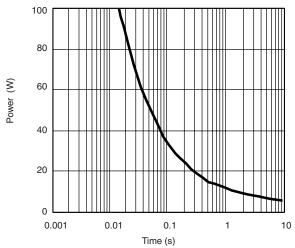
On-Resistance vs. Gate-to-Source Voltage

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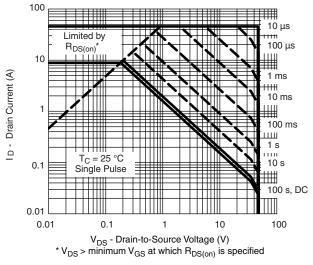
VISHAY

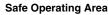
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

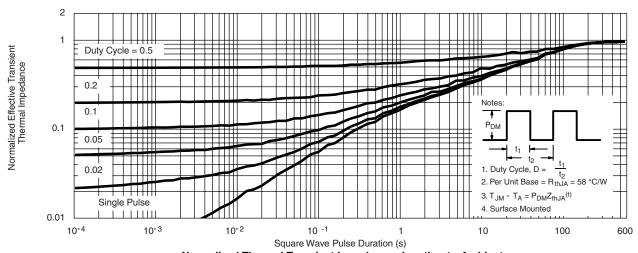




Single Pulse Power, Juncion-To-Ambient



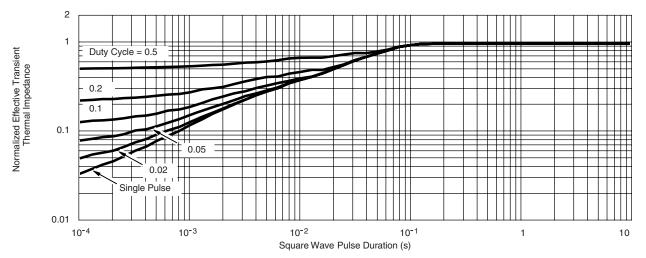




Normalized Thermal Transient Impedance, Junction-to-Ambient



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?71874.



DWG: 5881

PowerPAK® SO-8, (Single/Dual)



	3. Dimensions exclusive of mold flash and cutting burrs.							
		MILLIMETERS		INCHES				
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.		
A	0.97	1.04	1.12	0.038	0.041	0.044		
A1		-	0.05	0	-	0.002		
b	0.33	0.41	0.51	0.013	0.016	0.020		
С	0.23	0.28	0.33	0.009	0.011	0.013		
D	5.05	5.15	5.26	0.199	0.203	0.207		
	4.00	4.00	F 00	0.400	0.400	0.407		

Α	0.97	1.04	1.12	0.038	0.041	0.044		
A1		-	0.05	0	-	0.002		
b	0.33	0.41	0.51	0.013	0.016	0.020		
С	0.23	0.28	0.33	0.009	0.011	0.013		
D	5.05	5.15	5.26	0.199	0.203	0.207		
D1	4.80	4.90	5.00	0.189	0.193	0.197		
D2	3.56	3.76	3.91	0.140	0.148	0.154		
D3	1.32	1.50	1.68	0.052	0.059	0.066		
D4		0.57 typ.			0.0225 typ.			
D5		3.98 typ.			0.157 typ.			
E	6.05	6.15	6.25	0.238	0.242	0.246		
E1	5.79	5.89	5.99	0.228	0.232	0.236		
E2 (for AL product)	3.30	3.48	3.66	0.130	0.137	0.144		
E2 (for other product)	3.48	3.66	3.84	0.137	0.144	0.151		
E3	3.68	3.78	3.91	0.145	0.149	0.154		
E4 (for AL product)		0.58 typ.			0.023 typ.			
E4 (for other product)		0.75 typ.		0.030 typ.				
е		1.27 BSC		0.050 BSC				
K (for AL product)		1.45 typ.		0.057 typ.				
K (for other product)		1.27 typ.		0.050 typ.				
K1	0.56	-	=	0.022	-	=		
Н	0.51	0.61	0.71	0.020	0.024	0.028		
L	0.51	0.61	0.71	0.020	0.024	0.028		
L1	0.06	0.13	0.20	0.002	0.005	0.008		
θ	0°	-	12°	0°	-	12°		
W	0.15	0.25	0.36	0.006	0.010	0.014		
M	0.125 typ.			0.005 typ.				
ECN: C13-0702-Rev. K, 20)-May-13			•				

Revison: 20-May-13 Document Number: 71655



RECOMMENDED MINIMUM PADS FOR PowerPAK® SO-8 Single



Recommended Minimum Pads Dimensions in Inches/(mm)

Return to Index

APPLICATION NOTE



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